TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

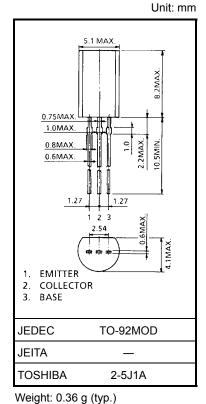
# 2SC5201

High-Voltage Switching Applications

- High breakdown voltage: VCEO = 600 V
- Low saturation voltage: V<sub>CE</sub> (sat) = 1.0 V (max) (I<sub>C</sub> = 20 mA, I<sub>B</sub> = 0.5 mA)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	600	V	
Collector-emitter voltage		V <sub>CEO</sub>	600	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	Ι <sub>C</sub>	50	mA	
	Pulse	I <sub>CP</sub>	100		
Base current		Ι <sub>Β</sub>	25	mA	
Collector power dissipation		P <sub>C</sub>	900	mW	
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	−55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e.

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operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook

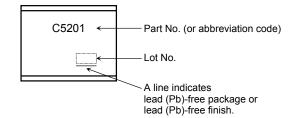
("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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## Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 600 V, I <sub>E</sub> = 0	_	_	1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	1	μA
Collector-emitter breakdown voltage	V <sub>CEO</sub>	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 0	600	_	_	V
DC current gain	h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	80	_	_	
	h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 20 mA	100	_	300	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 20 mA, I <sub>B</sub> = 0.5 mA	_	_	1.0	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 20 mA	—	0.66	0.85	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	6.5	_	pF

## Marking



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